

FAST RECOVERY DIODES

Stud Version

Features

- High power FAST recovery diode series
- 1.0 to 2.0 μs recovery time
- High voltage ratings up to 2500V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Compression bonded encapsulation
- Stud version JEDEC DO-205AB (DO-9)
- Maximum junction temperature 125°C

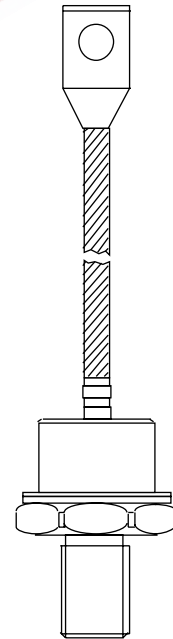
200A

Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

Major Ratings and Characteristics

| Parameters | SD203N/R | Units |
|------------------|-------------|-------------------|
| $I_{F(AV)}$ | 200 | A |
| @ T_C | 85 | °C |
| $I_{F(RMS)}$ | 314 | A |
| I_{FSM} @ 50Hz | 4990 | A |
| @ 60Hz | 5230 | A |
| I^2t @ 50Hz | 125 | KA ² s |
| @ 60Hz | 114 | KA ² s |
| V_{RRM} range | 400 to 2500 | V |
| t_{rr} range | 1.0 to 2.0 | μs |
| @ T_J | 25 | °C |
| T_J | - 40 to 125 | °C |



case style
DO-205AB (DO-9)

SD203N/R Series

Bulletin I2064 rev. A 09/94

International
IR Rectifier

ELECTRICAL SPECIFICATIONS

Voltage Ratings

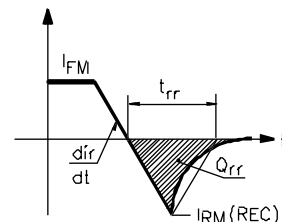
| Type number | Voltage Code | V_{RRM} max. repetitive peak and off-state voltage V | V_{RSM} , maximum non-repetitive peak voltage V | I_{RRM} max. $T_J = 125^\circ\text{C}$ mA |
|---------------|--------------|---|--|---|
| SD203N/R..S10 | 04 | 400 | 500 | 35 |
| | 08 | 800 | 900 | |
| | 10 | 1000 | 1100 | |
| SD203N/R..S15 | 12 | 1200 | 1300 | |
| | 14 | 1400 | 1500 | |
| | 16 | 1600 | 1700 | |
| SD203N/R..S20 | 20 | 2000 | 2100 | |
| | 25 | 2500 | 2600 | |

Forward Conduction

| Parameter | SD203N/R | Units | Conditions |
|---|----------|--------------------|--|
| $I_{F(AV)}$ Max. average forward current @ Case temperature | 200 | A | 180° conduction, half sine wave. |
| | 85 | °C | |
| $I_{F(RMS)}$ Max. RMS current | 314 | A | DC @ 76°C case temperature |
| I_{FSM} Max. peak, one-cycle non-repetitive forward current | 4990 | A | t = 10ms No voltage |
| | 5230 | | t = 8.3ms reapplied |
| | 4200 | | t = 10ms 100% V_{RRM} |
| | 4400 | | t = 8.3ms reapplied |
| I^2t Maximum I^2t for fusing | 125 | KA ² s | t = 10ms No voltage |
| | 114 | | t = 8.3ms reapplied |
| | 88 | | t = 10ms 100% V_{RRM} |
| | 81 | | t = 8.3ms reapplied |
| $I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing | 1250 | KA ² √s | t = 0.1 to 10ms, no voltage reapplied |
| $V_{F(TO)1}$ Low level of threshold voltage | 1.00 | V | (16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ max. |
| $V_{F(TO)2}$ High level of threshold voltage | 1.47 | | ($I > \pi \times I_{F(AV)}$), $T_J = T_J$ max. |
| r_{f1} Low level of forward slope resistance | 1.10 | mΩ | (16.7% $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ max. |
| r_{f2} High level of forward slope resistance | 0.46 | | ($I > \pi \times I_{F(AV)}$), $T_J = T_J$ max. |
| V_{FM} Max. forward voltage | 1.65 | V | $I_{pk} = 628\text{A}$, $T_J = 25^\circ\text{C}$, $t_p = 400 \mu\text{s}$ square pulse |

Recovery Characteristics

| Code | $T_J = 25^\circ\text{C}$ typical t_{rr} @ 25% I_{RRM} (μs) | Test conditions | | | Max. values @ $T_J = 125^\circ\text{C}$ | | |
|------|--|---------------------------------|--------------------------------|--------------|--|-------------------------------|-----------------|
| | | I_{pk} Square Pulse (A) | di/dt (A/ μs) | V_r (V) | t_{rr} @ 25% I_{RRM} (μs) | Q_{rr} (μC) | I_{rr} (A) |
| S10 | 1.0 | 750 | 25 | -30 | 2.4 | 52 | 33 |
| S15 | 1.5 | | | | 2.9 | 90 | 44 |
| S20 | 2.0 | | | | 3.2 | 107 | 46 |



Thermal and Mechanical Specification

| Parameter | SD203N/R | Units | Conditions |
|---|-----------------|-------|--|
| T _J Max. operating temperature range | -40 to 125 | °C | |
| T _{stg} Max. storage temperature range | -40 to 150 | | |
| R _{thJC} Max. thermal resistance, junction to case | 0.115 | K/W | DC operation |
| R _{thCS} Max. thermal resistance, case to heatsink | 0.08 | | Mounting surface, smooth, flat and greased |
| T Mounting torque ±10% | 31 | Nm | Not lubricated threads |
| | 24.5 | | Lubricated threads |
| wt Approximate weight | 250 | g | |
| Case style | DO-205AB (DO-9) | | See Outline Table |

ΔR_{thJC} Conduction

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

| Conduction angle | Sinusoidal conduction | Rectangular conduction | Units | Conditions |
|------------------|-----------------------|------------------------|-------|--------------------------------------|
| 180° | 0.010 | 0.008 | K/W | T _J = T _J max. |
| 120° | 0.013 | 0.014 | | |
| 90° | 0.017 | 0.019 | | |
| 60° | 0.025 | 0.027 | | |
| 30° | 0.044 | 0.044 | | |

Ordering Information Table

Device Code

| | | | | | | | | |
|----|----|---|---|----|-----|---|---|---|
| SD | 20 | 3 | R | 25 | S20 | P | B | C |
| ① | ② | ③ | ④ | ⑤ | ⑥ | ⑦ | ⑧ | ⑨ |

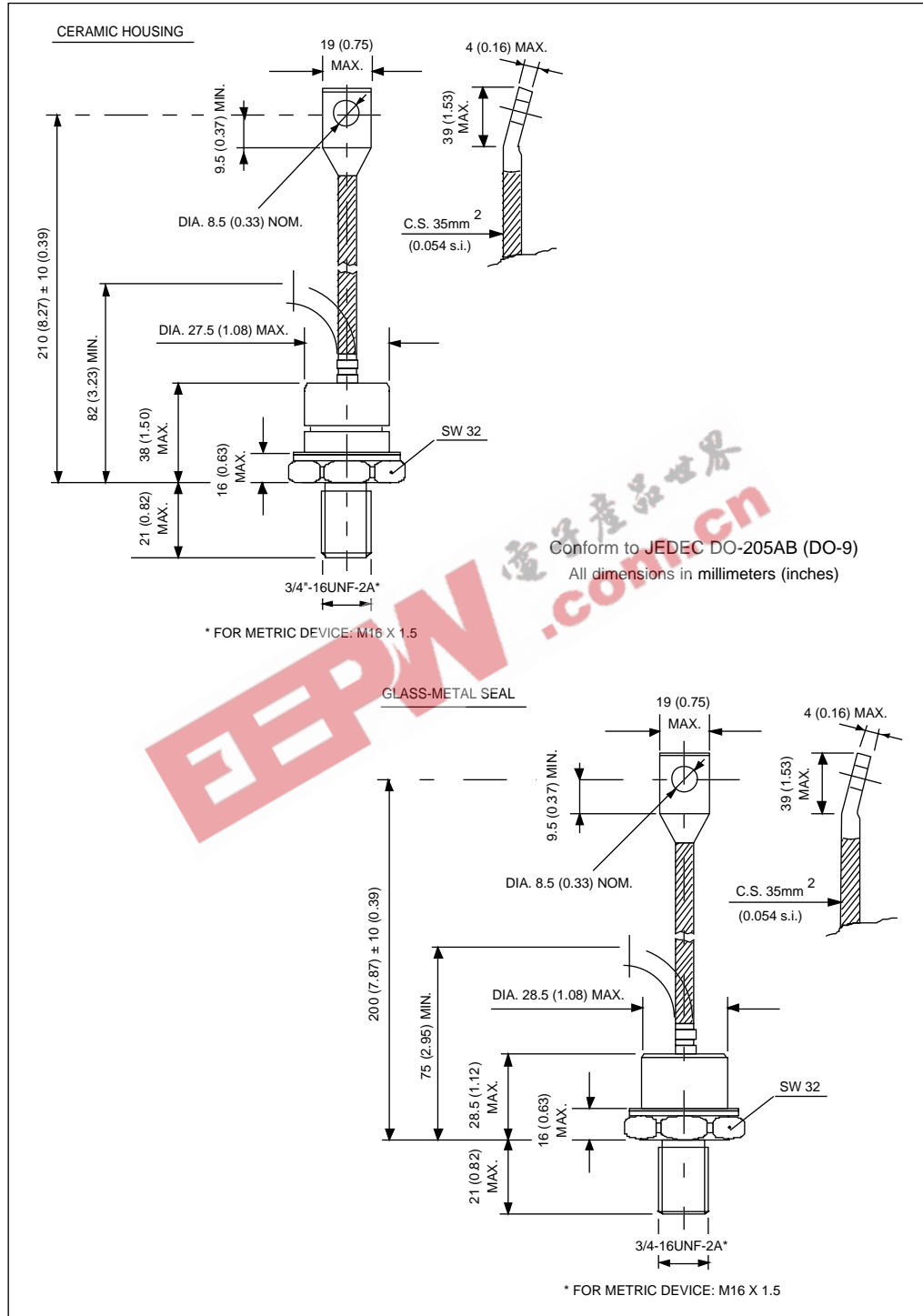
- 1** - Diode
- 2** - Essential part number
- 3** - 3 = Fast recovery
- 4** - N = Stud Normal Polarity (Cathode to Stud)
R = Stud Reverse Polarity (Anode to Stud)
- 5** - Voltage code: Code x 100 = V_{RRM} (see Voltage Ratings table)
- 6** - t_{rr} code (see Recovery Characteristics table)
- 7** - P = Stud base DO-205AB (DO-9) 3/4" 16UNF-2A
M = Stud base DO-205AB (DO-9) M16 X 1.5
- 8** - B = Flag top terminals (for Cathode/ Anode Leads)
S = Isolated lead with silicone sleeve
(Red = Reverse Polarity; Blue = Normal Polarity)
None = Not isolated lead
- 9** - C = Ceramic housing (over 1600V)
V = Glass-metal seal (only up to 1600V)

SD203N/R Series

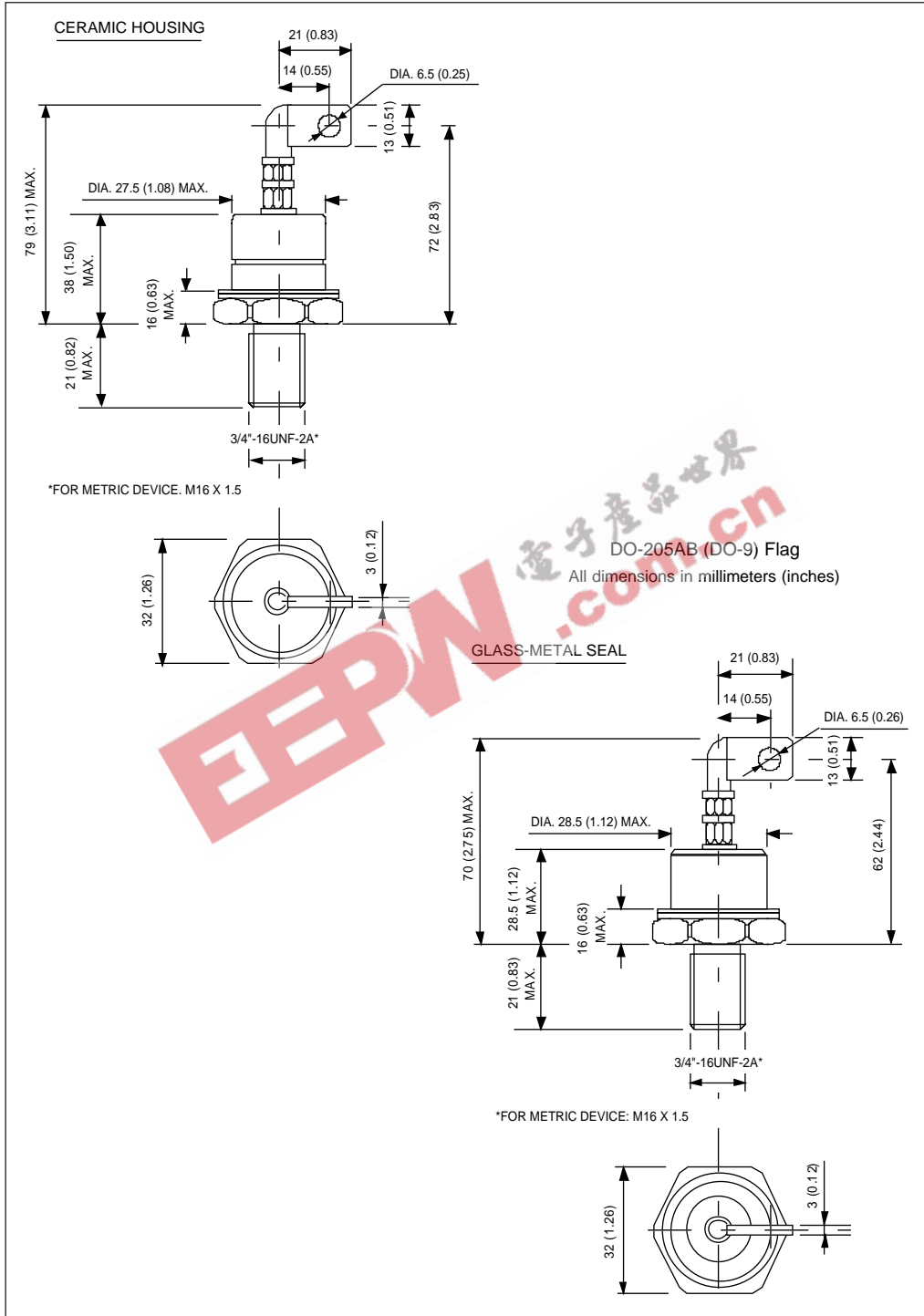
Bulletin I2064 rev. A 09/94

International
IRF Rectifier

Outline Table



Outline Table



SD203N/R Series

Bulletin I2064 rev. A 09/94

International
IRF Rectifier

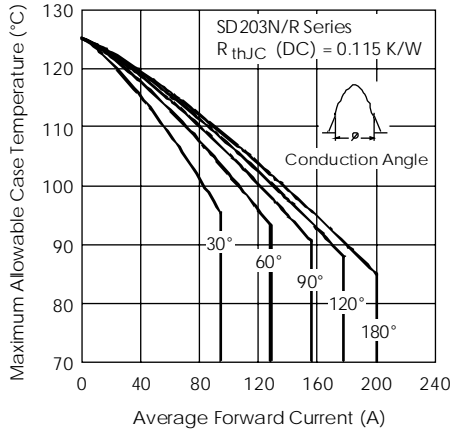


Fig. 1 - Current Ratings Characteristics

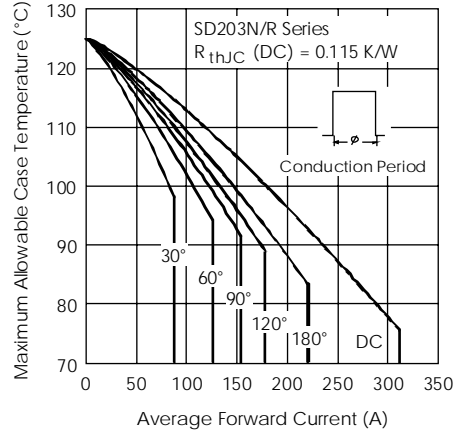


Fig. 2 - Current Ratings Characteristics

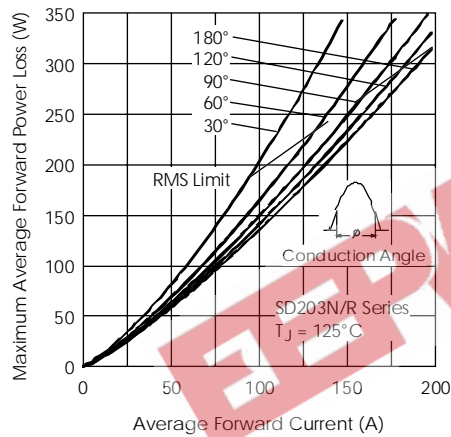


Fig. 3 - Forward Power Loss Characteristics

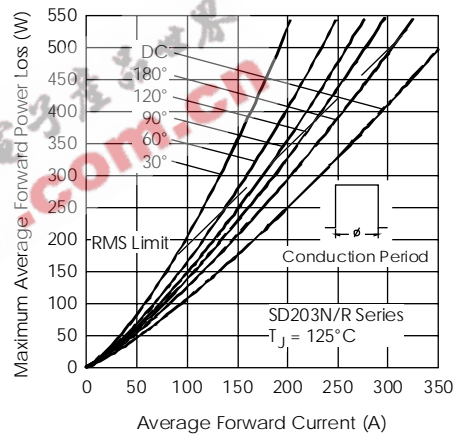


Fig. 4 - Forward Power Loss Characteristics

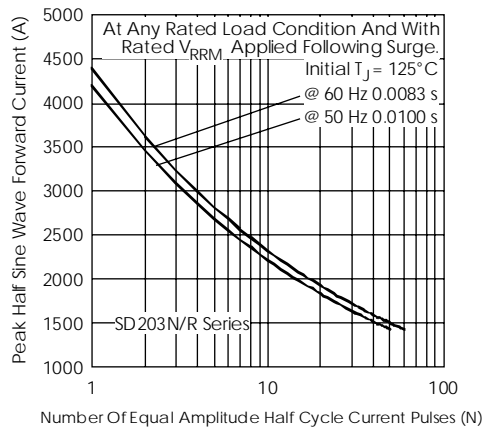


Fig. 5 - Maximum Non-repetitive Surge Current

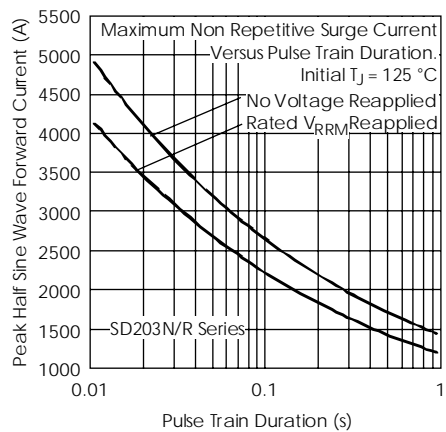


Fig. 6 - Maximum Non-repetitive Surge Current

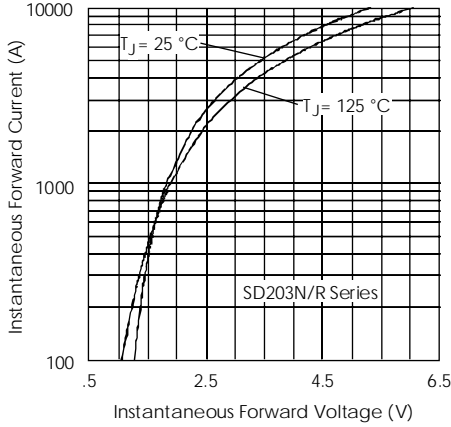


Fig. 7 - Forward Voltage Drop Characteristics

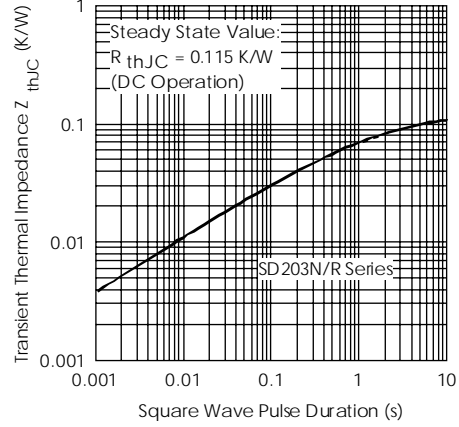


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

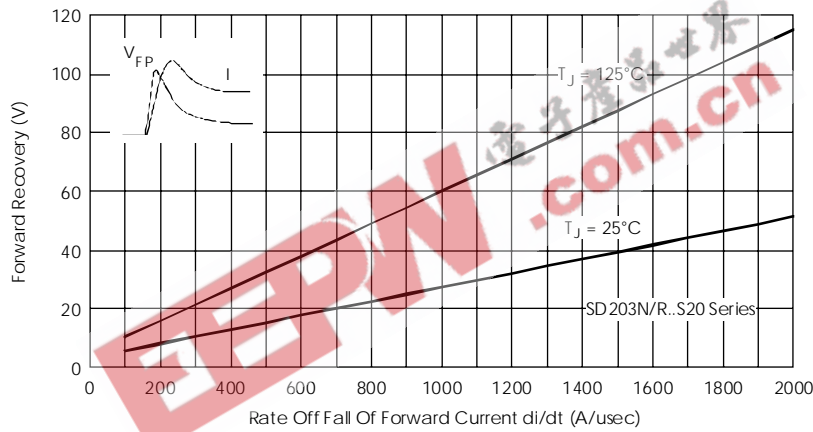


Fig. 9 - Typical Forward Recovery Characteristics

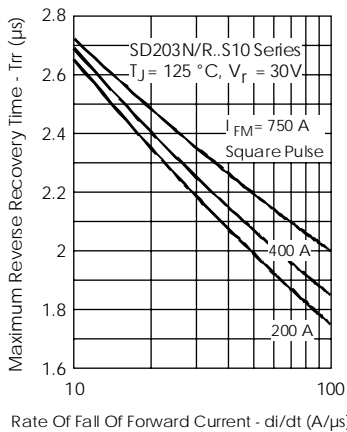


Fig. 10 - Recovery Time Characteristics

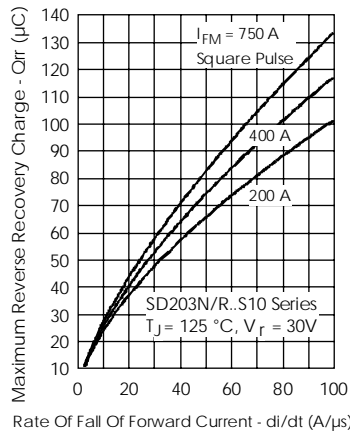


Fig. 11 - Recovery Charge Characteristics

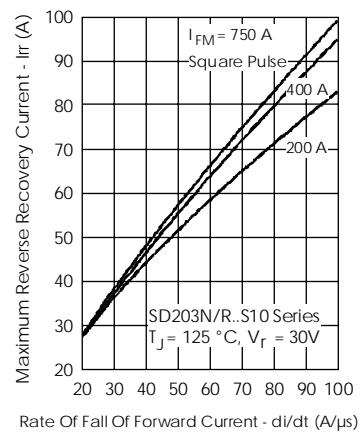


Fig. 12 - Recovery Current Characteristics

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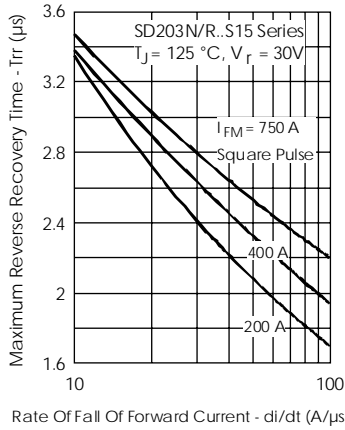


Fig. 13 - Recovery Time Characteristics

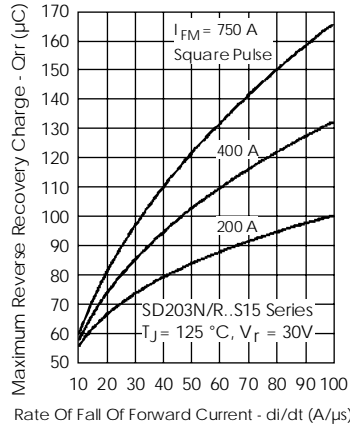


Fig. 14 - Recovery Charge Characteristics

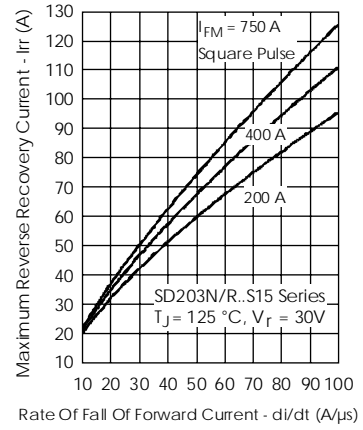


Fig. 15 - Recovery Current Characteristics

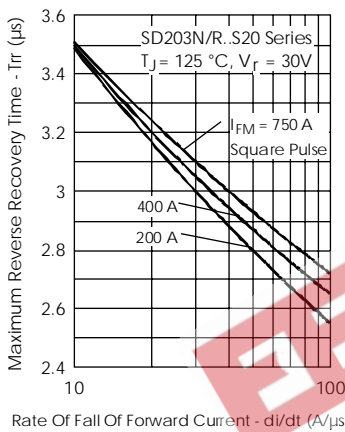


Fig. 16 - Recovery Time Characteristics

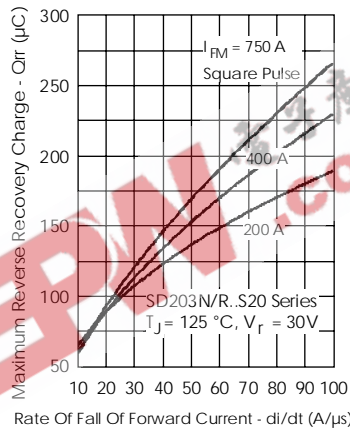


Fig. 17 - Recovery Charge Characteristics

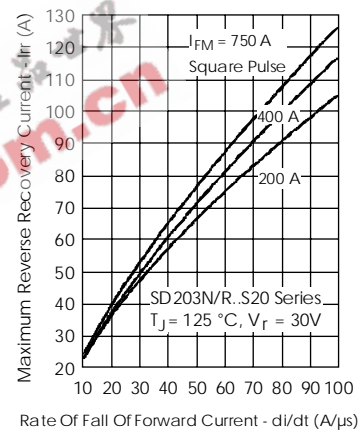


Fig. 18 - Recovery Current Characteristics

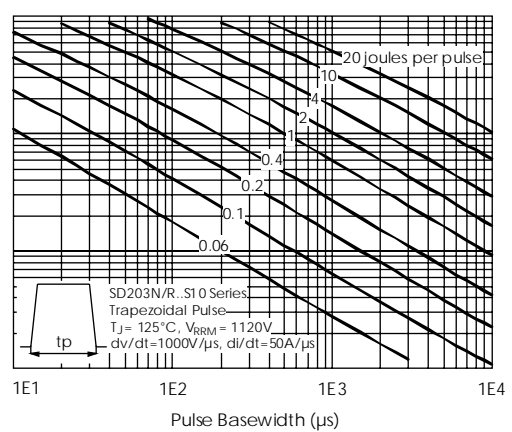
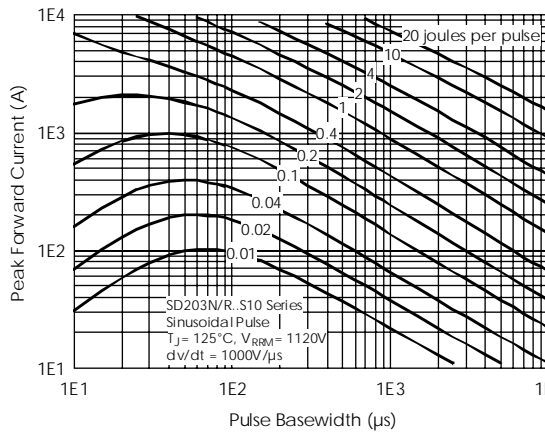


Fig. 19 - Maximum Total Energy Loss Per Pulse Characteristics

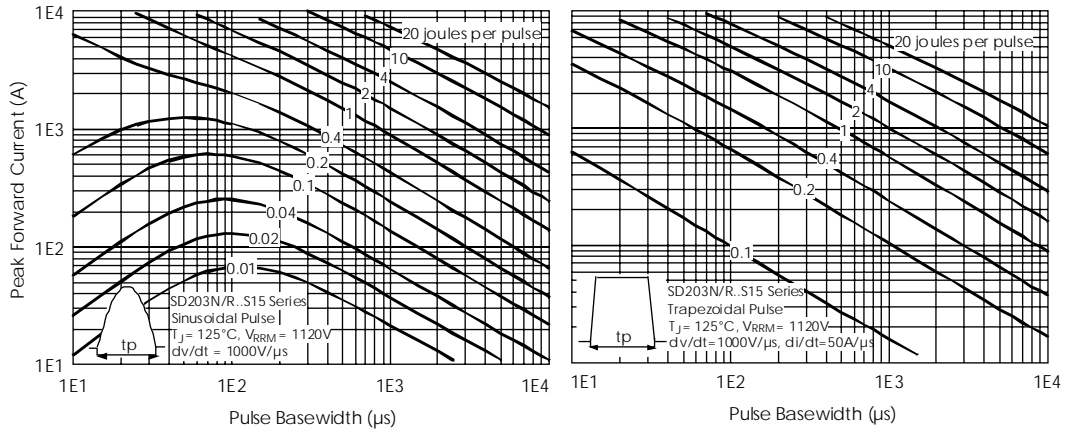


Fig. 20 - Maximum Total Energy Loss Per Pulse Characteristics

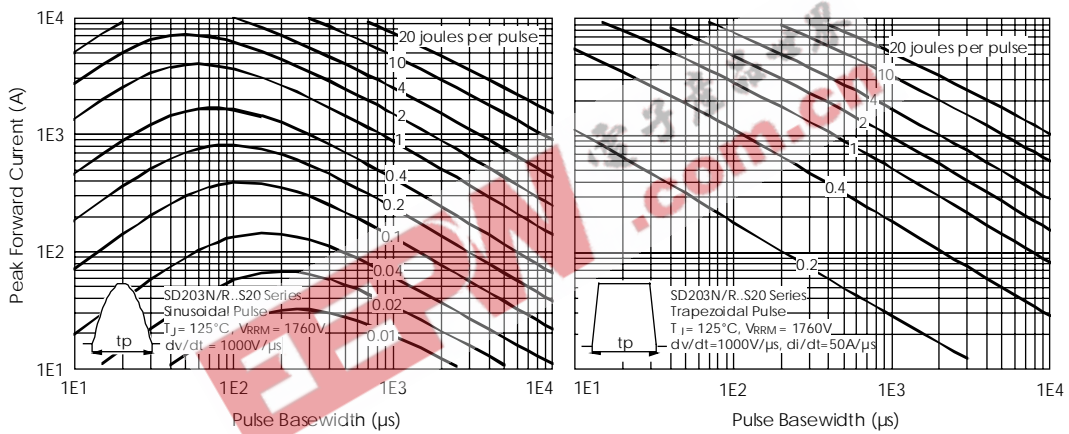


Fig. 21 - Maximum Total Energy Loss Per Pulse Characteristics